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# Effects of N-doped concentration in graphene on CO<sub>2</sub> adsorption

# Ong Kim Le<sup>1,2</sup>, Viorel Chihaia<sup>3</sup>, Do Ngoc Son<sup>1,2,\*</sup>



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<sup>1</sup>Ho Chi Minh City University of Technology (HCMUT), 268 Ly Thuong Kiet Street, District 10, Ho Chi Minh City, Vietnam

<sup>2</sup>Vietnam National University Ho Chi Minh City, Linh Trung Ward, Ho Chi Minh City, Vietnam

<sup>3</sup>Institute of Physical Chemistry "Ilie Murgulescu" of the Romanian Academy, Splaiul Independentei 202, Sector 6, 060021 Bucharest, Romania

#### Correspondence

**Do Ngoc Son**, Ho Chi Minh City University of Technology (HCMUT), 268 Ly Thuong Kiet Street, District 10, Ho Chi Minh City, Vietnam

Vietnam National University Ho Chi Minh City, Linh Trung Ward, Ho Chi Minh City, Vietnam

Email: dnson@hcmut.edu.vn

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#### ABSTRACT

Solving the problem of the environment related to CO<sub>2</sub> emission is an urgent and challenging task to prevent the escalation of climate change, which is due to increasing energy demand from fossil fuels and industrial activities. Using graphene to capture CO<sub>2</sub> gas is of great interest to mitigate global warming, where  $CO_2$  capture by doped graphene has been shown to significantly improve the CO<sub>2</sub> adsorption capacity compared to that of pure graphene. In particular, N-doped graphene is a unique structure that was suggested for CO<sub>2</sub> capture by the adsorption phenomenon. However, there is no research available to clarify nitrogen doping concentration in graphene on CO<sub>2</sub> adsorption. Therefore, this work has been devoted to elucidating the problem using the density functional theory method considering van der Waals interaction. We showed that increasing the doping content of nitrogen by 3.1, 6.3, 9.4, and 12.5 % will increase the CO<sub>2</sub> adsorption energy, monotonically for N content below 9.4 % and significantly for 12.5 %. The most favorable adsorption configuration of the CO<sub>2</sub> molecule should be parallel to the surface of the N-doped graphene. The structure of the substrate at 12.5 % N distorted upon the CO<sub>2</sub> adsorption; therefore, the substrate is more active for CO<sub>2</sub> capture. The physical meaning underlying the interaction of the N@graphene system is physisorption, which is due to the contribution of the N  $p_z$  state and the CO<sub>2</sub>  $p_z$  state along the surface normal of the substrate. Increasing the N-doping content shifts down the unoccupied states of the N  $p_z$  orbital in the conduction band across the Fermi level to the valence band. Hence, the population of the occupied state at the Fermi level increases as increasing the N-doping concentration, leading to the stronger interaction of the CO<sub>2</sub> molecule with the N@graphene substrate. The results should be useful for the rational design of suitable N@graphene substrates for  $CO_2$  capture and storage applications.

**Key words:** Toxic gas, Capture, Doping, Two-dimensional materials, Density functional theory, Physical properties

#### INTRODUCTION

Capturing and storing  $CO_2$  by adsorption is a viable method attracting much attention to control the amount of  $CO_2$  released into the environment, which is the cause of climate change. Finding suitable adsorbents for efficient and low-cost  $CO_2$  capture is challenging for researchers. Various  $CO_2$ adsorbents such as zeolites<sup>1</sup>, amine-enriched carbon sorbent<sup>2</sup>, hydrotalcite-like compound<sup>3</sup>, molecular sieves<sup>4</sup>, metal-organic frameworks<sup>5</sup>, carbonbased materials<sup>6</sup>, porous graphene and nitrogendoped graphene<sup>7-10</sup> have been investigated.

Graphene is not only a transparent material with a large surface area, high mechanical strength, and high carrier mobility but also has a good surface structure for the CO<sub>2</sub> adsorption sites<sup>7</sup>. Doping graphene with N could offer high CO<sub>2</sub> adsorption capacity<sup>10</sup>. The N atoms in the graphene structure enhanced the interaction energies<sup>10</sup>. Many approaches have been used to fabricate N-doped graphene<sup>11,12</sup>. Experimental results showed that CO<sub>2</sub> adsorption capability significantly increased when doping nitrogen in

the pyridinic and pyrrolic forms<sup>9</sup>. Theoretical studies have demonstrated that graphitic-doping nitrogen is more stable than the pyridinic and pyrrolic forms in the free-standing graphene layer<sup>13</sup>. Generally, the literature ha analyzed the CO<sub>2</sub> adsorption on the N@graphene system<sup>14,15</sup>. However, no studies are available to clarify the influences of the N concentration on CO<sub>2</sub> adsorption. Therefore, we investigated the CO<sub>2</sub> adsorption on the N@graphene system based on density function theory calculations with van der Waals interaction by analyzing the geometric structures and physical properties of the N@graphene system. Graphitic nitrogen concentrations vary from 3.1, 6.3, and 9.4, to 12.5 %.

## **METHOD**

In the present work, we analyzed the geometric structure, total energy, and electronic properties of  $CO_2$ on the N@graphene using the van der Waals density functional theory method integrated into the VASP code<sup>16–20</sup>. The exchange-correlation energy was considered by using the Perdew-Burke-Ernzerhof gen-

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eralized gradient approximation (GGA-PBE)<sup>21-23</sup>. The valence electron-ion interactions were described by using the projector-augmented-wave method<sup>24,25</sup>. We used Monkhorst-Pack's special k-point sampling technique with a 3×3×1 k-point grid for structure optimization and total energy calculation<sup>26</sup>. The planewave cutoff energy was 400 eV. We used the Gaussian smearing of order 0 with the width of 0.1 eV for a better convergence speed of the calculations. The N@graphene system was modeled using the 4x4 unit cell with a vacuum space of 18 Å in a perpendicular direction to the surface of the N@graphene system. Allatom positions of the N@graphene/CO2 system were fully relaxed during the geometry optimization with the upper criterion of 0.001 eVÅ<sup>-1</sup> for interatomic forces.

To evaluate the adsorption capacity of  $CO_2$  on the N@graphene, we used the following formula:

$$E_a = E_{sub+CO_2} - (E_{sub} + E_{CO_2}),$$
(1)

where,  $E_{sub+CO_2}$  is the total energy of N@graphene/CO<sub>2</sub> system.  $E_{sub}$  and  $E_{CO_2}$ ) are total energies of clean substrate and isolated CO<sub>2</sub>, respectively.

## **RESULTS AND DISCUSSION**

#### Substrates of N@graphene

We optimized the possible structure of the N@graphene substrates according to the nitrogen content of 3.1, 6.3, 9.4, and 12.5 % by substituting one, two, three, and four nitrogen atoms into the graphene unit cell, respectively. The N-doping content in graphene varying from 3.1 to 9.4 % has been investigated previously for other applications<sup>27,28</sup>. We focused only on the close arrangement of the N atoms in the unit cell because the far-away dispersion will approach the case of the single N atom doping<sup>28</sup>. The optimized structures were listed in Figure 1, where, N1, N2, N3, and N4 are the denotation for the substitution of one, two, three, and four N atoms, respectively. The A, B, C, and D symbols represented the position of the N atoms in the graphene unit cell. For doping one N atom (3.1 %), all possibilities are equivalent and denoted as N1. For doping two and more N atoms, we considered four structures (N<sub>2AA</sub>, N<sub>2AB</sub>, N<sub>2AC</sub>, and N<sub>2AD</sub>) for 6.3 %, two structures (N<sub>3AAB</sub> and N<sub>3ABB</sub>) for 9.4 %, and four structures (N4AABD, N4AABB, N4AABC, and N4AADD) for 12.5 %. For each percent of doping, there are many possible arrangement of the N atoms. However, for the selected substrates, we have shown in the following parts that we had found the simple rule

of the adsorption energy of  $CO_2$  molecule on the N content. We also optimized the unit cell size for each N content; however, they remain almost the same as that of the pure graphene.

### CO<sub>2</sub> molecule on N@graphene substrates

We investigated CO<sub>2</sub> adsorption on the optimized N@graphene substrates by initially placing the CO<sub>2</sub> molecule with parallel and incline configurations with a distance of 3 Å to the surface. We first performed a structural optimization, then calculated CO<sub>2</sub> adsorption energy. Table 1 showed that all the calculated values of adsorption energy are negative. The more negative adsorption energy, the more stable the configuration of the CO2 adsorption will be. The favorable order of the CO<sub>2</sub> adsorption is  $N_{2AA} > N_{2AC}$  $> N_{2AD} > N_{2AB}$  for 6.3 %,  $N_{3ABB} \approx N_{3AAB}$  for 9.4 %, and  $N_{4AADD} > N_{4AABB} > N_{4AABD} > N_{4AABC}$  for 12.5 % N. The favorable order of the CO2 adsorption on the N2 substrates is similar to that of water on the N@graphene<sup>28</sup>. Therefore, the most favorable adsorption configuration of the CO<sub>2</sub> molecule was found on the N1, N2AA, N3ABB, and N4AADD substrates for the N-doping percentage of 3.1, 6.3, 9.4, and 12.5 %, respectively. Shown in Figure 2 is the most favorable adsorption configuration for each Ndoping content.

The CO<sub>2</sub> molecule in the most favorable adsorption configuration locates almost parallel to the substrates' surface, see Figure 2. The average bond length to the surface is about 3.19 Å for the N1, N2, and N3 substrates. However, the bond length becomes shorter than 3.0 Å for the N<sub>4</sub> substrate. The configuration, adsorption energy, and bond length to the N1 slab of the CO<sub>2</sub> molecule are in good agreement with the study<sup>15</sup>. Two oxygen atoms on top of the N atoms offer the most favorable adsorption configuration of CO2 on N2AA. For the N3ABB slab, the C atom of the CO<sub>2</sub> molecule on the hollow site of the benzene ring and one oxygen atom on the top of the C atom nearest to one N atom in the substrate should be the most favorable configuration. For the N4AADD substrate, the C-O bond of CO<sub>2</sub> is parallel to the N-N bond in the substrate, while the left oxygen atom of CO2 is on the hollow site of the benzene ring.

Figure 3 shows the dependence of the  $CO_2$  adsorption energy on the N-doped concentration in graphene. The adsorption energy monotonically decreases, and the adsorption strength increases as the doping content increases. With doping content 3.1, 6.3, and 9.4 %, the behavior is linear; however, it becomes significantly more negative for 12.5 % N. This behavior of







**Figure 2**: The most favorable adsorption configuration of  $CO_2$  on the N@graphene substrates with nitrogen atom content of 3.1, 6.3, 9.4, and 12.5 % in that order. The carbon atom of graphene (gray), the nitrogen atom (blue), the oxygen atom (red), and the C atom of  $CO_2$  molecule (green).

Table 1: CO <sub>2</sub> adsorption energy is <b>E</b> <sub>a</sub> (eV), and <b>d</b> <sub>g</sub>	as-sub (Å) is the average bond length of the CO <sub>2</sub> molecule with
the substrate surface	

N-doping content (%)		$E_a$ (	eV)		$d_{gas-sub}$ (Å)
3.1	-0.312 N <sub>1</sub>				3.17 N <sub>1</sub>
6.3	-0.325 N <sub>2AA</sub>	-0.316 N <sub>2AD</sub>	-0.322 N <sub>2AC</sub>	-0.310 N <sub>2AB</sub>	3.21 N <sub>2AA</sub>
9.4	-0.338 N <sub>3ABB</sub>	-0.337 N <sub>3AAB</sub>			3.19 N <sub>3ABB</sub>
12.5	-0.343 N <sub>4AABB</sub>	-0.324 N4 <sub>AABC</sub>	-0.326 N <sub>4AABD</sub>	-0.549 N <sub>4AADD</sub>	2.96 N <sub>4AADD</sub>

the adsorption energy on the N-doping content can be explained when considering the changes in the geometry and electronic properties.



Analyzing the substrate ' structure before and after the  $CO_2$  adsorption showed that no significant changes have been found for the N-doped content from 3.1 to 9.4 %. When the N-doped content increased to 12.5 %, the geometrical structure of the substrate had a buckling shape around the  $CO_2$  adsorption site compared with the structure of the clean substrate, see Figure 4. Figure 4b shows that the A1 and D2 atoms moved up about 0.01 Å; while A2 and D1 moved down about 0.02 Å in comparison to the isolated substrate structure Figure 4a. The total undulating distance is about 0.03 Å.

# **Electronic properties of N@graphene/CO**<sub>2</sub> system

The interaction between  $CO_2$  and the graphene substrate can be explained via the Bader charge analysis, as shown in Table 2. We found that the O and C atoms of  $CO_2$  molecule always accumulate and donate charge, respectively. Also, the N and C atoms of the graphene substrate gain and lose charge in that order. The result is that the  $CO_2$  molecule gain the negative charge from the graphene substrates. We also find that the charge exchange is small for 3.1, 6.3, and 9.4 % N, while it is significant for 12.5 % N. This behavior is consistent with that of adsorption energy analyzed above.

To understand which electronic states of  $CO_2$  and the N@graphene dominate the interaction, we analyzed the density of states, as visualized in Figure 5.

As the N-doping content increases, the unoccupied state of the N  $p_z$  orbital in the conduction band shift down across the Fermi level to the valence band. The higher the N doping content, the more the occupied state of N  $p_z$  will become. Therefore, the population

of the occupied state at the Fermi level increases, leading to a stronger interaction of the CO2 molecule with the substrates because the occupied states of the substrates will attract the unoccupied  $p_x$ ,  $p_y$ , and  $p_z$  states of CO2. Upon increasing the N content, these states of CO2 move closer to the Fermi level, leading to a stronger interaction with the occupied state of N  $p_7$ . Especially, for the N content of 3.1, 6.3, and 9.4 %, the unoccupied states of the CO2 molecule do not cross the Fermi level. Therefore, the charge exchange is ignorable, while it is significant due to the unoccupied state of CO<sub>2</sub>  $p_z$  crossing the Fermi level for the N doping content of 12.5 %. Thereby, the interaction of the CO<sub>2</sub> molecule with the substrates is the electrostatic attraction for 3.1, 6.3, and 9.4 %, and the charge exchange for 12.5 % N. This finding agrees with the analysis of Bader's charge above. We can state that the  $CO_2 p_z$  state becoming occupied is the reason for the charge exchange of the N@graphene system and significantly enhanced the CO<sub>2</sub> adsorption energy for 12.5 % N. As observed in Figure 6, the charge clouds of the N atoms and the oxygen atoms exhibit the shape of  $p_z$  orbitals (look like bowling pin along the surface normal).

# CONCLUSION

We have elucidated the influences of the N concentration in graphene on CO<sub>2</sub> adsorption by the van der Waals density functional theory approach. Our results showed that the  $p_z$  orbital state of the doped nitrogen shifted down to increase the occupied states at the Fermi level upon the increase of N doping. These occupied states of the N atoms enhanced the interaction with the CO2 unoccupied states to increase the CO2 adsorption energy. Particularly, the unoccupied state of CO<sub>2</sub>  $p_z$  orbital partially becoming the occupied state lying in the top region of the valence band increased the charge exchange and significantly enhanced the adsorption energy of CO2 for 12.5 % N over linear region 0.0, 3.1, 6.3, and 9.4 % N. The findings contribute to the knowledge of the interaction between the N@graphene and CO2 for applications in CO<sub>2</sub> capture and sensors.

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## **COMPETING INTERESTS**

The authors declare that they have no competing interests.



**Figure 4**: The structure of the 12.5 % N substrate before (a) and after (b) the CO<sub>2</sub> adsorption. A1, D1, A2, and D2 denote the N atoms.

N content (%)	3.1	6.3	9.4	12.5
20	4.015	4.013	4.017	4.167
С	-4.000	-4.000	-4.000	-4.000
CO <sub>2</sub>	0.015	0.013	0.017	0.167
All	2.621	5.343	8.288	10.764
All C <sub>substrate</sub>	-2.636	-5.356	-8.305	-10.931
Substrate	-0.015	-0.013	-0.017	-0.167

Table 2: Bader charge (e<sup>-</sup>) for CO<sub>2</sub> adsorbed on N@graphene: (+) charge gain, (-) charge loss



**Figure 5**: Projected DOS of CO<sub>2</sub> molecule on the N@graphene substrates with different nitrogen contents, i.e., (a) 3.1 %, (b) 6.3 %, (c) 9.4 %, and (d) 12.5 %. The C  $p_x$  and C  $p_y$  states of the substrates are completely overlapping.

# **AUTHORS' CONTRIBUTIONS**

Ong Kim Le: investigation, visualization, formal analysis, writing manuscript, reviewing and editing Viorel Chihaia: resources, supervision, reviewing and editing

Do Ngoc Son: Conceptualization, formal analysis, resources, supervision, validation, writing manuscript, reviewing and editing

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# Ảnh hưởng nồng độ pha tạp N trong graphene lên hấp phụ CO $_2$

Ông Kim Lẹ<sup>1,2</sup>, Viorel Chihaia<sup>3</sup>, Đỗ Ngọc Sơn<sup>1,2,\*</sup>



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## TÓM TẮT

Giải quyết vấn đề môi trường liên quan đến phát thải CO<sub>2</sub> là nhiệm vụ cấp bách và thách thức nhằm ngăn chặn sự leo thang của biến đổi khí hậu, do nhu cầu năng lượng từ nhiên liệu hóa thạch và các hoạt động công nghiệp ngày càng tăng. Sử dụng graphene để bắt giữ khí CO $_2$  rất được quan tâm để giảm thiểu sự nóng lên toàn cầu, trong đó việc thu giữ CO $_2$  bằng graphene pha tạp đã được chứng minh là cải thiên đáng kể khả năng hấp phụ CO<sub>2</sub> so với graphene nguyên chất. Đặc biệt, graphene pha tạp N là một cấu trúc độc đáo được đề xuất để thu giữ CO $_2$  bằng hiện tượng hấp phụ. Tuy nhiên, hiện chưa có nghiên cứu nào làm rõ ảnh hưởng nồng độ pha tạp nitơ trong graphene đối với sự hấp phụ CO2. Do đó, công trình này được dành để làm sáng tỏ vấn đề bằng cách sử dụng phương pháp lý thuyết phiếm hàm mật độ có xem xét tương tác van der Waals. Chúng tôi đã chỉ ra rằng, việc tăng hàm lượng nitơ pha tạp lên 3,1, 6,3, 9,4 và 12,5% sẽ làm tăng năng lượng hấp phụ CO $_2$ , một cách đơn điệu đối với hàm lượng N dưới 9,4% và rất đáng kế đối với 12,5%. Cấu hình hấp phụ thuận lợi nhất của phân tử CO $_2$  là song song với bề mặt của graphene pha tạp N. Cấu trúc của chất nền ở 12,5% N bị biến dạng khi hấp phụ CO<sub>2</sub>; do đó, là chất nền có mức độ hoạt hóa cao hơn để thu giữ CO $_2$ . Ý nghĩa vật lý làm cơ sở cho tượng tác của hệ N@graphene chính là sự hấp phụ vật lý, do sự đóng góp của trạng thái N  $p_z$  và trạng thái CO $_2$  $p_z$  dọc theo phương pháp tuyến bề mặt của chất nền. Việc tăng hàm lượng pha tạp N làm dịch chuyển các trạng thái không chiếm giữ của quỹ đạo N p<sub>z</sub> trong vùng dẫn vượt qua mức Fermi sang vùng hóa trị. Do đó, mật độ trạng thái bị chiếm ở mức Fermi tăng lên khi tăng nồng độ pha tạp N, dẫn đến tương tác mạnh hơn của phân tử CO<sub>2</sub> với chất nền N@graphene. Các kết quả thu được sẽ hữu ích cho việc thiết kế các chất nền N@graphene phù hợp cho các ứng dụng thu giữ và lưu trữ CO<sub>2</sub>

Từ khoá: Khí độc, Bắt giữ, Pha tạp, Vật liệu hai chiều, Lý thuyết phiếm hàm mật độ, Tính chất vật lý

<sup>1</sup>Trường Đại học Bách Khoa TP. Hồ Chí Minh (HCMUT), 268 Đường Lý Thường Kiệt, Quận 10, TP. Hồ Chí Minh, Việt Nam.

<sup>2</sup>Đại học Quốc gia Tp. Hồ Chí Minh, Phường Linh Trung, TP. Hồ Chí Minh, Việt Nam.

<sup>3</sup>Viện Hóa lý "Ilie Murgulescu" thuộc Viện hàn lâm Romania, Splaiul Independentei 202, Sector 6, 060021 Bucharest, Romania.

#### Liên hệ

Đỗ Ngọc Sơn, Trường Đại học Bách Khoa TP. Hồ Chí Minh (HCMUT), 268 Đường Lý Thường Kiệt, Quân 10, TP. Hồ Chí Minh, Việt Nam.

Đại học Quốc gia Tp. Hồ Chí Minh, Phường Linh Trung, TP. Hồ Chí Minh, Việt Nam.

Email: dnson@hcmut.edu.vn

Lịch sử

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